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(54) Title: A PROCESS FOR THE REMOVAL OF POLYMER THERMOSETS FROM A SUBSTRATE

(57) Abstract: The present invention relates to a process for the removal of polymer thermosets from the substrates without damaging the substrates. The present invention relates to a process for the removal of polymer thermoset from the substrate retaining the physical and chemical properties of the substrates. The present invention more particularly relates to the use of bio molecules for cleaving polymer thermosets and the process to perform the cleaving.



A PROCESS FOR THE REMOVAL OF POLYMER THERMOSETS FROM A SUBSTRATE

FIELD OF THE INVENTION

The present invention relates to a process for the removal or cleaving of polymer thermosets from the substrates without damaging the substrates. The present invention particularly relates to a process for the removal or cleaving of polymer thermosets from the substrates that are available for recycle or reuse. The present invention more particularly relates to a process for the removal of polymer thermoset from the substrate retaining the physical and chemical properties of the substrate. The present invention more particularly relates to the use of bio molecules for cleaving polymer thermosets and the process to perform the cleaving.

BACKGROUND OF THE INVENTION

Packaging and sealing are imperative in the efficient functioning of electronic devices, because they provide environmental protection, mechanical stability and thermal insulation to a device. The packaging and sealing material is usually applied on a device while it is a viscous liquid and allowed to cure. The curing process is initiated by simple mixing of polymer resin with a hardener. The resin comprises epoxy moieties and the hardener comprises either amine or acid functionalities. Upon mixing, the facile reaction between the amine functionalities of the hardener and the epoxy functionalities of the resin results in the formation of highly cross-linked polymer network that are known as polymer thermosets (PTs). Such a network is responsible for the desired properties of the PTs, paradoxically they also make the PTs insoluble and infusible. Consequently, thorough removal of PTs without destroying underlying substrate is difficult or impossible, which in turn hinders the reuse of the substrates.

Thus there is a need to remove polymer thermosets completely from substrates without affecting or sacrificing the substrate and its physical and chemical properties. It is also observed that substrates that can be separated from thermosets without damage or loss in properties can result in tremendous economic benefits due to reuse and recycle.

Journal of Applied Polymer Science, Vol. 39, 1425-1437 (1990) and Journal of Applied Polymer Science, Vol. 39, 1439-1457 (1990) describes the reversible cross linking in epoxy resins. They have observed that the S-S bond can be cleaved under harsh conditions.

US 6,841,710, describes a process for degrading polymers of disulphide plastics has been reported, said process comprising adding to the disulphide plastics, an effective amount of a reducing agent having a thiol group and for fracturing the chemical bonds in said plastics and producing a variety of monomers and degradation products wherein said reducing agent is selected from a group of compounds having a thiol group.

US20090137777, discloses a specific poly epoxy compound having at least two olefin oxide groups and at least one tertiary ester group per molecule, a method for producing the compound, a thermosetting resin composition containing the compound, a cured product of the composition, and a method for removing the cured product; wherein said method for removing a cured product, comprises heating the whole or part of the cured product at a temperature higher than the heat-curing temperature to thermally cleave a tertiary ester bond derived from the poly epoxy compound (B), and removing the heated portion of the cured product by using or not using a treatment agent.

Removing polymer thermoset without destroying underlying substrates has not been demonstrated. Also prior art processes execute the process of removal of polymer thermoset at very harsh conditions, which is not very desirable. In fact, the harsh conditions are likely to destroy the substrate, which will eventually make the substrate unavailable for reuse.

Therefore, there is a need to provide agents that will cause cleavage of bonds and thus remove thermosets from substrate without damaging the substrate.

There is also a need to remove polymer thermoset from substrate in such a way that the substrate retains its physical and chemical properties.

Another need is that the agent and the process to remove polymer thermoset from substrate is mild and works in mild process conditions. As mentioned earlier, if the condition is harsh, the substrate is destroyed. Therefore, a mild condition is required for thermoset removal that renders the possibility of substrate reuse.

OBJECTIVE OF THE INVENTION

The primary objective of the present invention is to provide a process for the removal or cleaving of polymer thermosets from the substrate without the damage of the substrates.

Another objective of the present invention is to provide a process for the removal or cleaving of polymer thermosets from the substrates that are available for recycle or reuse.

Yet another objective of the present invention is to provide a process to remove polymer thermoset from substrate such that the substrate retain its inbuilt properties and characteristics.

Yet another objective of the present invention is to provide a process to remove polymer thermoset from substrate in mild conditions.

SUMMARY OF THE INVENTION

Accordingly the present invention relates to a process for the removal of polymer thermoset from a substrate by using cleaving agent without damaging the substrate and the said process comprising the steps of: (i) providing polymer thermoset coated substrate, (ii) preparing 10 to 50% cleaving agent solution in a solvent, (iii) removing the polymer thermoset by dipping the substrate as provided in step (i) in cleaving agent solution as prepared in step (ii) for a period in the range of 2 to 6 h at a temperature in the range of 20°C to 100°C, more preferably in the range of 22 to 40°C to obtain the undamaged substrate on the removal of polymer thermoset.

In a preferred aspect polymer thermoset used in step (i) is an epoxy resin containing cross linker having at least one S-S bond.

In another aspect of the present invention the cross linker is cystamine.

Yet in another aspect of the present invention the cleaving agent used in step (ii) comprises oxidizing or reducing molecules particularly bio molecules.

Yet in another aspect of the present invention the bio molecules comprises peptides, proteins or enzymes or combination thereof.

Yet in another aspect of the present invention the biomolecules are selected from the group consisting of glutathione, thioredoxin, peroxiredoxin or dithiothreitol (DTT) or combination thereof.

Yet in another aspect of the present invention the substrate used in step (i) are made of material consisting of glass, silicon, ITO (Indium-doped Tin Oxide) coated glass, metal, metal alloy, semi conductor and polymers.

In another aspect of the present invention the use of biomolecules, comprises of peptides, proteins or enzymes for the removal of polymer thermosets from the substrate, without damaging the substrate.

BRIEF DESCRIPTION OF THE DRAWINGS

Figure 1: SEM image of the removal of polymer thermosets from transparency sheet substrate.

Figure 2: SEM image of the removal of polymer thermosets from copper sheet substrate.

Figure 3: SEM image of the removal of polymer thermosets from ITO coated glass substrate.

Figure 4: SEM image of the removal of epoxy thermoset from transistor substrates.

DETAILED DESCRIPTION OF THE INVENTION

While the invention is susceptible to various modifications and alternative forms, specific aspect thereof has been shown by way of example and graphs and will be described in detail below. It should be understood, however that it is not intended to limit the invention to the particular forms disclosed, but on the contrary, the invention is to cover all modifications, equivalents, and alternative falling within the spirit and the scope of the invention as defined by the appended claims.

The Applicants would like to mention that the examples are mentioned to show only those specific details that are pertinent to understanding the aspects of the present invention so as not to obscure the disclosure with details that will be readily apparent to those of ordinary skill in the art having benefit of the description herein.

The terms “comprises”, “comprising”, or any other variations thereof, are intended to cover a non-exclusive inclusion, such that a process, biomolecules, thermosets, cross linkers that comprises a list of components does not include only those components but may include other components not expressly listed or inherent to such process. In other

words, one or more elements in a system or process proceeded by “comprises... a” does not, without more constraints, preclude the existence of other elements or additional elements in the system or process.

In the following detailed description of the aspects of the invention, reference is made to the accompanying graphs that form part hereof and in which are shown by way of illustration specific aspects in which the invention may be practiced. The aspects are described in sufficient details to enable those skilled in the art to practice the invention, and it is to be understood that other aspects may be utilized and that changes may be made without departing from the scope of the present invention. The following description is, therefore, not to be taken in a limiting sense, and the scope of the present invention is defined only by the appended claims.

Accordingly the present invention relates to a process for the removal or cleaving of polymer thermoset from a substrate by using cleaving agent without damaging the substrate and the said process comprising the steps of: (i) providing polymer thermoset coated substrate, (ii) preparing 10 to 50% cleaving agent solution in a solvent, (iii) removing the polymer thermoset by dipping the substrate as provided in step (i) in cleaving agent solution as prepared in step (ii) for a period in the range of 2 to 6 h at a temperature in the range of 20°C to 100°C, more preferably in the range of 22 to 40°C to obtain the undamaged substrate on the removal of polymer thermoset.

In a preferred aspect polymer thermoset used in step (i) is an epoxy resin containing cross linker having at least one S-S bond.

In another aspect of the present invention the cross linker is cystamine.

Yet in another aspect of the present invention the cleaving agent used in step (ii) comprises oxidizing or reducing molecules particularly bio molecules.

Yet in another aspect of the present invention the bio molecules comprises peptides, proteins or enzymes or combination thereof.

Yet in another aspect of the present invention the biomolecules are selected from the group consisting of glutathione, thioredoxin, peroxiredoxin or dithiothreitol (DTT) or combination thereof.

Yet in another aspect of the present invention the substrate used in step (i) are made of material consisting of glass, silicon, ITO (Indium-doped Tin Oxide) coated glass,

metal, metal alloy, semi conductor and polymers.

In another aspect of the present invention the solvent used is water, methanol, ethanol, chloroform or acetonitrile or combinations thereof.

In another aspect of the present invention the use of biomolecules, comprises of peptides, proteins or enzymes for the removal of polymer thermosets from a substrate, without damaging the substrate.

Present invention provides a process for the removal or cleaving of polymer thermosets from the specific substrate leaving behind substrates that are undamaged and available for recycle or reuse wherein the cleaving agent selected from oxidizing and reducing molecules and biomolecules that can separate polymer thermosets from substrates without making any damage to substrate and loss in the substrate's physical and chemical properties in mild conditions. Glutathione is exemplified as the cleaving agent.

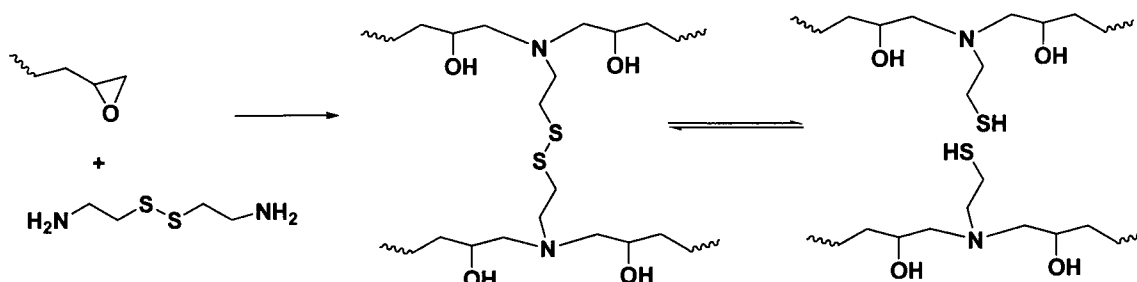
To achieve the present objective of providing a solution for removing polymer thermoset completely without affecting the substrate and its physical and chemical properties, the present invention propose the use of agents comprising oxidizing or reducing molecules or biomolecules. The biomolecules of the present invention are selected from, but not limited to peptides, proteins or enzymes. For the purpose of ease in the description, these agents will be referred to as "Cleaving agents".

More particularly the present invention is a one step process of contacting the polymer thermoset with the solution of the cleaving agent resulting in the removal of the thermoset leaving behind the intact substrate, wherein the substrate is coated with a cleavable cross linker.

The process conditions are:

Temperature: ambient (20° C to 40° C)

Pressure: ambient (760 mmHg)



The cleaving agent of the invention comprises oxidizing and reducing molecules, particularly biomolecules. The biomolecules of the invention comprises peptides, proteins and enzymes. The bio molecules of the invention are more particularly glutathione, thioredoxin, peroxiredoxin and Dithiothreitol (DTT).

The cleavable cross linker should have at least one S-S bond, preferably cystamine.

The solution of the cleaving agent is prepared in solvents that can be aqueous or nonaqueous or combinations thereof. The cleaving agents are dissolved in water, methanol, ethanol, chloroform, acetonitrile or in combinations thereof. They are used to cleave at room temperature (20°C-40° C).

Process is carried out at a temperature in the range of 20°C - 100°C. Substrates are made of material of construction selected from glass, silicon, Indium-doped Tin Oxide (ITO) coated glass, metal, metal alloy, semi conductor and polymers. In case of ITO coated glass, the thickness of ITO varies depending on the manufacturer.

The room temperature (20°C-40°C) process of removing the polymer thermoset from a substrate without damaging the substrate at mild conditions comprises:

- i. providing polymer thermoset coated substrate, particularly epoxy type polymer thermoset mixed with cross linker having S-S bond;
- ii. dipping the polymer thermoset coated substrate as provided in step (i) with cleaving agent for period in the range of 2 h to 6 h, at atmospheric pressure (760 mmHg) and ambient temperature (20°C - 40°C).

EXAMPLES

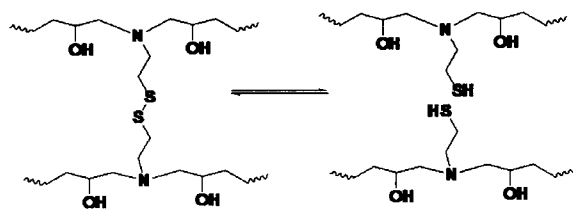
The following examples are given by way of illustration therefore should not be construed to limit the scope of the present invention.

EXAMPLE 1

Epoxy resin (0.58 g) was mixed with cystamine (0.12 g) to form a viscous mass. . One half of the transparency sheet was coated with the cleavable epoxy thermoset (viscous

mass) as shown in Figure 1. The coating was allowed to dry for 6 h at 30°C temperature. (A temperature outside the range 20 to 40 °C doesn't have an adverse effect.) After curing the 1/4th of the sheet was immersed in cleaving agent. i.e glutathione (10% solution in water) for 2 h. This step removed epoxy thermoset from the substrate, wherever it was in contact with cleaving agent

The thermoset in the dipped portion degraded and came off from the surface during the glutathione exposure. The disulfide functionality that is an integral part of the crosslinker is converted to thiol, leading to breakage in cross linking.



The substrate was dried and characterized by SEM (Scanning Electrom Microscopy) to study the effect of coating and removal of epoxy thermoset. It was observed that there were no discernible changes on the surface due to the coating and removal of thermosets. Figure 1 represents the removal of polymer thermosets from transparency sheet substrate.

EXAMPLE 2

One half of the copper sheet was coated with the cleavable epoxy thermoset. After curing as discussed in Example 1 the 1/4th of the sheet was immersed in cleaving agent. This step removed epoxy thermoset from the substrate, which was exposed to cleaving agent (glutathione). Polymer thermosets was removed from copper sheet substrate. This is necessary because many of the transistors used in electronic circuit board are coated with thermoset. Thus, removal of thermoset from copper would enable the reuse of electronic circuit board. The substrate was characterized by SEM to study the effect of coating and removal of epoxy thermoset. Figure 2 represents removal of polymer thermosets from copper sheet substrate.

EXAMPLE 3

ITO (indium doped tin oxide) was coated with thermoset and removed as exemplified in example 1. The thickness of ITO on glass is 30 nm. While a thermoset is removed from such surface, there are two possibilities (i) thin ITO layer may come off with the thermoset or (ii) small amount of thermoset is left on the surface. In both the scenarios, the conducting ITO becomes an insulator that would make the ITO unusable. To test this, poly(3,4-ethylenedioxythiophene) (PEDOT) was electro synthesized on a ITO coated glass (ITO is a conductor) and on the thermoset coating removed from the ITO coated glass. In both the said cases (PEDOT) was electro synthesized on the ITO. Hence, ITO was conductor before and after the removal of thermoset coating and maintaining its physical and chemical properties. There are no discernible changes between the coated-removed surface and uncoated surface as shown in Figure 3. The pH of the solution was 7 and the experiment was carried out at atmospheric pressure (760 mmHg).

Figure 3 represents removal of polymer thermosets from ITO coated glass substrates followed by electrochemical deposition of poly (3, 4-ethylenedioxythiophene). Optoelectronic devices are encapsulated with thermoset to protect from atmospheric degradation. These devices comprise indium doped tin oxide (ITO). Indium is not abundantly available and is very expensive. Thus, reuse of ITO has economic benefits. Usually, a thin layer (~30 nm) is coated on top of glass substrate to render conductivity to an insulating substrate. The ITO coating thickness varies depending on the manufacturer. While removing thermoset from a ITO coated glass, two possibilities exist (i) ITO is damaged and removed from the substrate and (ii) thermoset is not completely removed. Both will lead to insulating domains, which will make the substrate unavailable for reuse. Herein, we demonstrate that the thermoset can be completely removed from ITO coated glass slide. We also show that the conductivity of the ITO is unaffected by electrodepositing poly (3,4-ethylenedioxythiophene).

EXAMPLE 4

Transistor substrates were coated with thermoset and removed. Figure 4 represents removal of epoxy thermoset from Transistor substrates. It was observed that the ~10

nm thick gold film is unaffected during the thermoset removal as characterized by SEM.

The advantages of the disclosed invention are thus attained in an economical, practical, and facile manner. While preferred aspects and example configurations have been shown and described, it is to be understood that various further modifications and additional configurations will be apparent to those skilled in the art. It is intended that the specific embodiments and configurations herein disclosed are illustrative of the preferred nature and best mode of practicing the invention, and should not be interpreted as limitations on the scope of the invention.

ADVANTAGES OF THE INVENTION

The main advantages of the present invention are

1. Removal of thermoset from substrate without affecting the substrate's physical and chemical properties.
2. The process is conducted under mild conditions such as neutral pH, room temperature and atmospheric pressure, making it an environmentally benign process.

CLAIMS:

1. A process for the removal of polymer thermoset from a substrate by using cleaving agent without damaging the substrate and the said process comprising the steps of:
 - i. providing a polymer thermoset coated substrate,
 - ii. preparing 10 to 50% cleaving agent solution in a solvent,
 - iii. removing the polymer thermoset by dipping the substrate as provided in step (i) in cleaving agent solution as prepared in step (ii) for a period in the range of 2 to 6 h at a temperature in the range of 20°C to 100°C to obtain the undamaged substrate on the removal of polymer thermoset.
2. The process as claimed in claim 1, wherein polymer thermoset used in step (i) is an epoxy resin containing cross linker having at least one S-S bond.
3. The process as claimed in claim 2, wherein the cross linker is cystamine.
4. The process as claimed in claim 1, wherein cleaving agent used in step (ii) comprises oxidizing or reducing molecules particularly bio molecules.
5. The process as claimed in claim 4, wherein bio molecules comprises peptides, proteins or enzymes or combination thereof.
6. The process as claimed in claim 4, wherein biomolecules are selected from the group consisting of glutathione, thioredoxin, peroxiredoxin or dithiothreitol (DTT) or combination thereof.
7. The process as claimed in claim 1, wherein substrate used in step (i) are made of material consisting of glass, silicon, ITO (Indium-doped Tin Oxide) coated glass, metal, metal alloy, semi conductor and polymers.
8. The process as claimed in claim 1, wherein solvent is water, methanol, ethanol, chloroform or acetonitrile or combinations thereof.
9. Use of biomolecules comprises of peptides, proteins or enzymes for the removal of polymer thermosets from a substrate, without damaging the substrate.

AMENDED CLAIMS

received by the International Bureau on 03 January 2012 (03.01.12)

1. A process for the removal of polymer thermoset from a substrate by using cleaving agent without damaging the substrate and the said process comprising the steps of:
 - i. providing a polymer thermoset coated substrate, wherein polymer thermoset is an epoxy resin containing cross linker having at least one S-S bond
 - ii. preparing 10 to 50% cleaving agent solution in a solvent,
 - iii. removing the polymer thermoset by dipping the substrate as provided in step (i) in cleaving agent solution as prepared in step (ii) for a period in the range of 2 to 6 h at a temperature in the range of 20°C to 100°C to obtain the undamaged substrate on the removal of polymer thermoset.
2. The process as claimed in claim 1, wherein the cross linker is cystamine.
3. The process as claimed in claim 1, wherein cleaving agent used in step (ii) comprises oxidizing or reducing molecules particularly bio molecules.
4. The process as claimed in claim 3, wherein bio molecules comprises peptides, proteins or enzymes or combination thereof.
5. The process as claimed in claim 3, wherein biomolecules are selected from the group consisting of glutathione, thioredoxin, peroxiredoxin or dithiothreitol (DTT) or combination thereof.
6. The process as claimed in claim 1, wherein substrate used in step (i) are made of material consisting of glass, silicon, ITO (Indium-doped Tin Oxide) coated glass, metal, metal alloy, semi conductor and polymers.

7. The process as claimed in claim 1, wherein solvent is water, methanol, ethanol, chloroform or acetonitrile or combinations thereof.
8. Use of biomolecules comprises of peptides, proteins or enzymes for the removal of polymer thermosets from a substrate, without damaging the substrate.

STATEMENT UNDER ARTICLE 19 (1)

Comments in respect of citations D1 and D2 is enclosed herewith,

The cited prior art D1 US5721204 relates to a paint stripping composition comprises of organic solvent and 0.2 to 20% of **peroxides**. The peroxides are well known strong oxidizing agents in the prior art. Hence, while using the composition of D1 to strip paint it will not be possible to strip the paint without damaging the surface. Whereas, the present invention is not using any peroxides for the removal of thermoset coatings from the substrate. The present invention relates to the removal of thermoset coating by using cleaving agent, which is entirely different from the cited D1 reference.

The cited reference D2 US6117829 discloses essentially a non-aqueous composition consisting essentially of a dibasic ester and a thickening agent which is soluble, swellable or dispersible in said dibasic ester. The said composition is useful for the removal of a chemical present on a substrate wherein said chemical is selected from the groups consisting of elastomeric and thermoset coating where the degree of cross-linking is minimal. Whereas, the present invention is not using dibasic ester and a thickening agent for the removal of thermoset coatings from the substrate. The present invention relates to the removal of thermoset coating by using cleaving agent, which is entirely different from the cited D1 reference.

After reviewing the citations of International Search report, the Applicants have amended the claims and amended claims are attached herewith.

In view of the above, the Applicants request to the learned Examiner to allow the claimed. Finally, the applicant believes that the amendments made to the claims are falling within the scope of original disclosure of the invention and no additional matter is added.

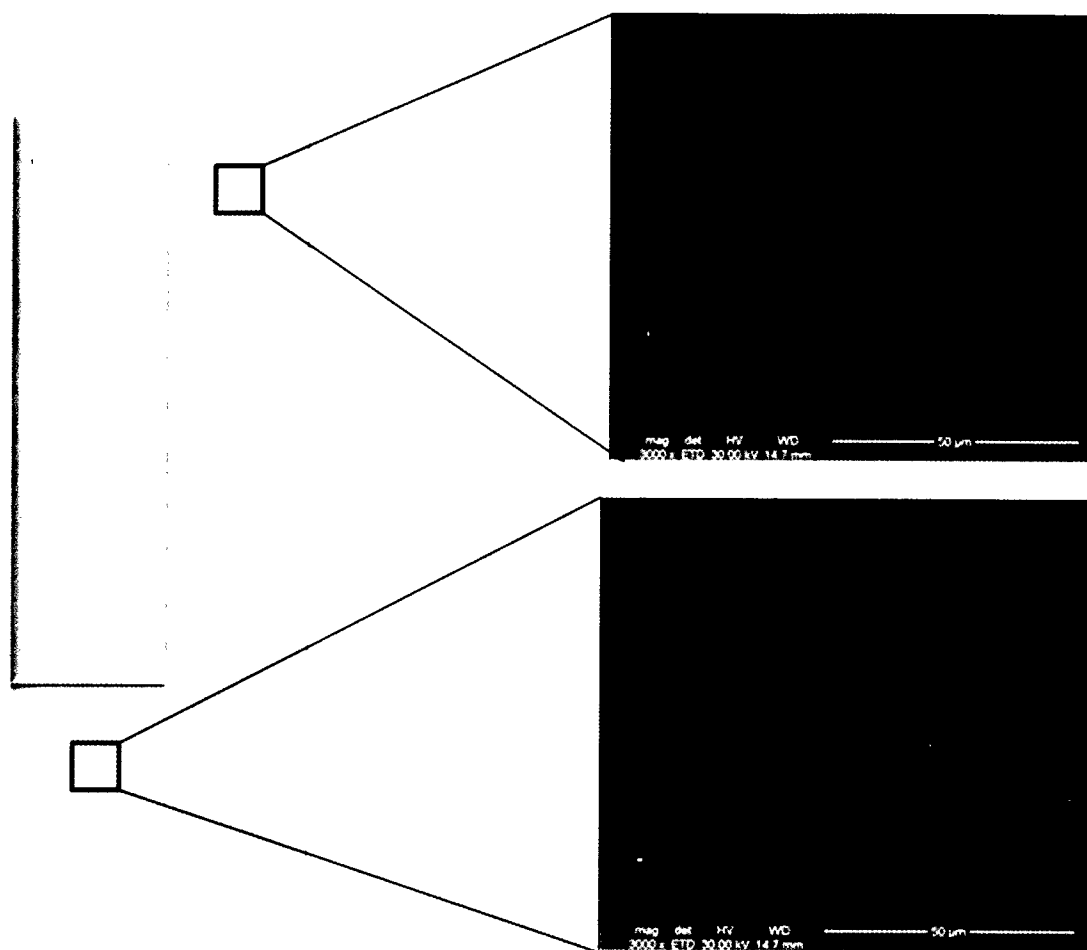


Figure 1

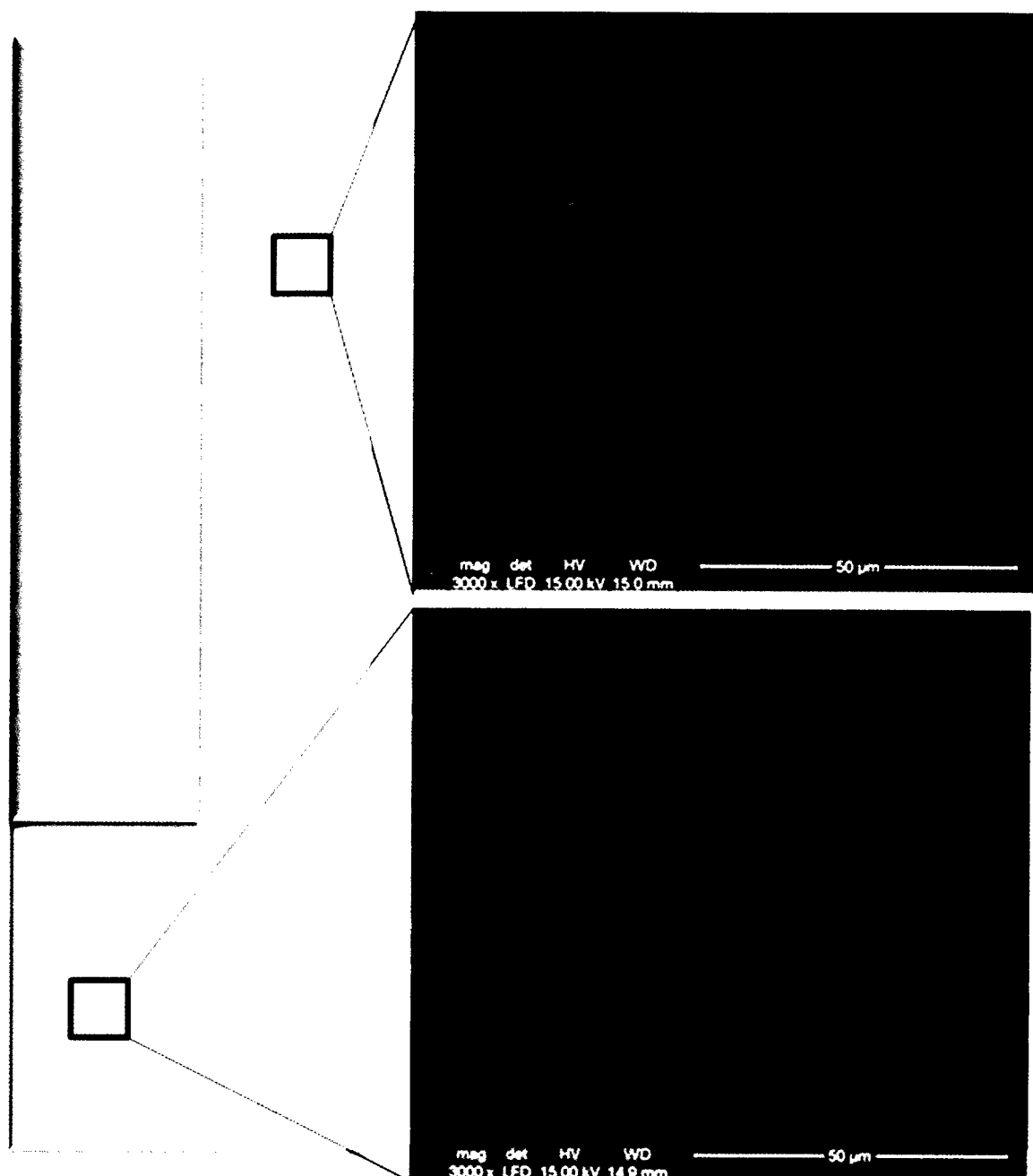


Figure 2

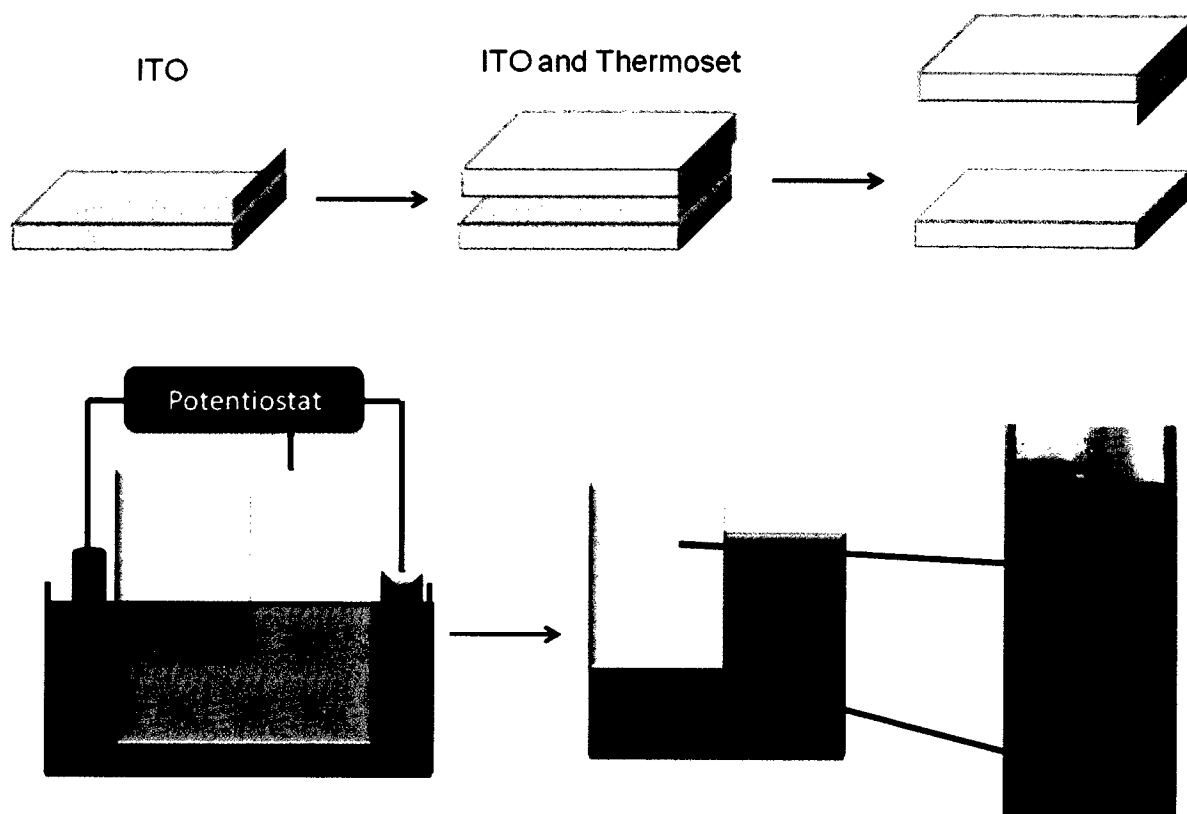


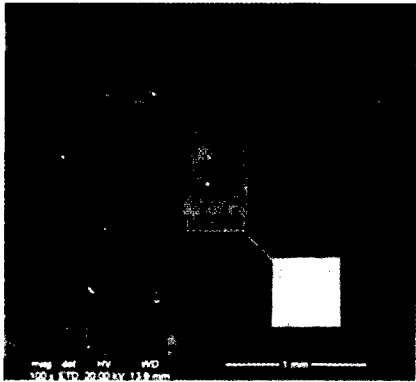
Figure 3



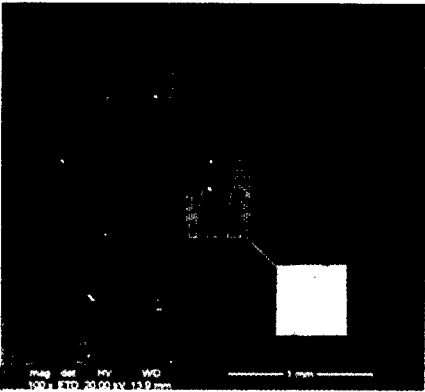
Coated Substrate



Coated and removed
Substrate



Uncoated Substrate



Uncoated Substrate

Figure 4

INTERNATIONAL SEARCH REPORT

International application No
PCT/IB2011/001821

A. CLASSIFICATION OF SUBJECT MATTER
INV. C09D9/00
ADD.

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)
C09D

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

EP0-Internal, WPI Data

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	US 5 721 204 A (MAXWELL JEFFREY W [US] ET AL) 24 February 1998 (1998-02-24) claim 6 column 6, line 29 - line 47 -----	1,3,4,7, 8
X	US 6 117 829 A (DIAZ IRIS MARGARITA [US] ET AL) 12 September 2000 (2000-09-12) claims 1,7,9,10,12,13 -----	1,7
A	US 2009/137777 A1 (IWASHIMA CHIAKI [JP] ET AL) 28 May 2009 (2009-05-28) cited in the application claims 1,811-14 -----	1



Further documents are listed in the continuation of Box C.



See patent family annex.

* Special categories of cited documents :

"A" document defining the general state of the art which is not considered to be of particular relevance

"E" earlier document but published on or after the international filing date

"L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)

"O" document referring to an oral disclosure, use, exhibition or other means

"P" document published prior to the international filing date but later than the priority date claimed

"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

"X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone

"Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.

"&" document member of the same patent family

Date of the actual completion of the international search

26 October 2011

Date of mailing of the international search report

03/11/2011

Name and mailing address of the ISA/

European Patent Office, P.B. 5818 Patentlaan 2
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Fax: (+31-70) 340-3016

Authorized officer

Niaounakis, Michael

INTERNATIONAL SEARCH REPORT

Information on patent family members

International application No

PCT/IB2011/001821

Patent document cited in search report		Publication date	Patent family member(s)	Publication date
US 5721204	A	24-02-1998	NONE	

US 6117829	A	12-09-2000	NONE	

US 2009137777	A1	28-05-2009	CN 101044183 A	26-09-2007
			EP 1803758 A1	04-07-2007
			WO 2006043608 A1	27-04-2006
			KR 20070084332 A	24-08-2007
